TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74AC138P,TC74AC138F,TC74AC138FN,TC74AC138FT

#### 3-to-8 Line Decoder

The TC74AC138 is an advanced high speed CMOS 3-to-8 LINE DECODER fabricated with silicon gate and double-layer metal wiring C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs ( $\overline{Y}0 - \overline{Y}7$ ) will go low.

When enable input G1 is held low or either  $\overline{G}2A$  or  $\overline{G}2B$  is held high, decoding function is inhibited and all outputs go high.

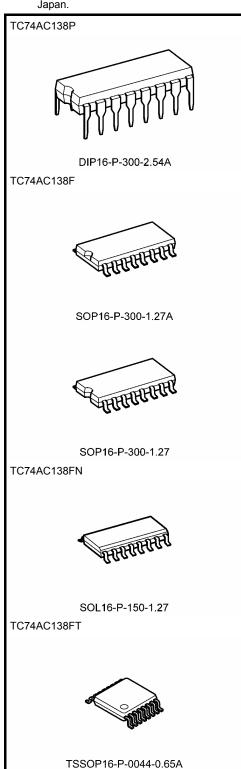
 $\overline{G}$ 1,  $\overline{G}$ 2A, and  $\overline{G}$ 2B inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### **Features**

- High speed:  $t_{pd} = 5.9 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 8 \mu A \text{ (max)}$  at  $T_{a} = 25 \text{°C}$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min)
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24$  mA (min) Capability of driving 50  $\Omega$  transmission lines.
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: VCC (opr) = 2 to 5.5 V
- Pin and function compatible with 74F138

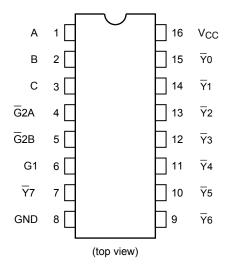
Note: xxxFN (JEDEC SOP) is not available in Japan.



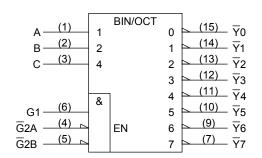
Weight

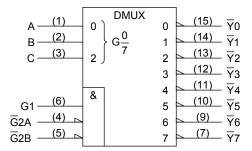
DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.) SOP16-P-300-1.27 : 0.18 g (typ.) SOL16-P-150-1.27 : 0.13 g (typ.) TSSOP16-P-0044-0.65A : 0.06 g (typ.)

# **Pin Assignment**



# **IEC Logic Symbol**





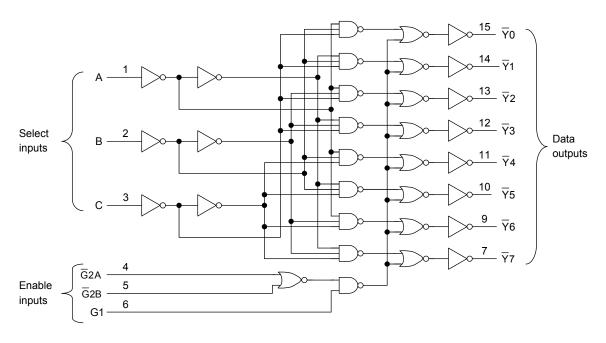
### **Truth Table**

Inputs					Outputs									
Enable			Select		₹0	<u>\text{Y}1</u>	<u></u>	<del>-</del> <del>-</del> <del>-</del> <del>-</del>	<u>¥</u> 4	<u>7</u> 5	<del>-</del> Y6	<del>-</del> 77	Selected Output	
G1	G <sub>2</sub> A	G <sub>2</sub> B	С	В	Α	10	T I	12	13	14	13	10	1 /	o aquat
L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None
Х	Н	X	X	Х	Х	Н	Н	Н	Η	Н	Н	Η	Η	None
Х	Х	Н	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	₹0
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	<del>Y</del> 1
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	₹2
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	<del>Y</del> 3
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	<del>Y</del> 4
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	₹5
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	₹6
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	₹7

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X: Don't care

### **Logic Diagram**



# **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	−0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	±20	mA
Output diode current	lok	±50	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±200	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	−65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

### **Recommended Operating Conditions (Note)**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V	
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	٧	
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	٧	
Operating temperature	T <sub>opr</sub>	−40 to 85	°C	
Input rise and fall time	dt/dV	0 to 100 (V <sub>CC</sub> = 3.3 ± 0.3 V)	ns/V	
input rise and rail time	αναν	0 to 20 (V <sub>CC</sub> = 5 ± 0.5 V)	115/ V	

Note: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



### **Electrical Characteristics**

### **DC Characteristics**

Characteristics	Symbol	Test Condition				Ta = 25°C		Ta = −40 to 85°C		Unit	
Characteristics	Cymbol				V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	<b>0</b> 1 <b>c</b>
		_			2.0	1.5	_	_	1.5	_	
High-level input voltage	V <sub>IH</sub>				3.0	2.10	_	_	2.10	_	V
				5.5	3.85	_	_	3.85	_		
Laurel Samuel		_		2.0	_	_	0.50	_	0.50	٧	
Low-level input voltage	$V_{IL}$			3.0	_	_	0.90	_	0.90		
					5.5	_	_	1.65	_	1.65	
			I <sub>OH</sub> = -50 μA	2.0	1.9	2.0	_	1.9	_		
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>			3.0	2.9	3.0	_	2.9	_	· v
High-level output	V <sub>OH</sub>				4.5	4.4	4.5	_	4.4	_	
voltage	- 011		$I_{OH} = -4 \text{ mA}$		3.0	2.58	_	_	2.48	_	
			$I_{OH}$ = -24 mA		4.5	3.94	_	_	3.80	_	
			$I_{OH} = -75 \text{ mA}$	(Note)	5.5	_	_	_	3.85	_	
		V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA		2.0	_	0.0	0.1	_	0.1	
					3.0	_	0.0	0.1	_	0.1	
Low-level output	$V_{OL}$				4.5	_	0.0	0.1	_	0.1	V
voltage	· OL		$I_{OL}$ = 12 mA		3.0	_	_	0.36	_	0.44	•
			$I_{OL}$ = 24 mA		4.5	_	_	0.36	_	0.44	
			I <sub>OL</sub> = 75 mA	(Note)	5.5	_	_	_	_	1.65	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	_	±1.0	μΑ	
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND			5.5	_	_	8.0	_	80.0	μΑ

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.



# AC Characteristics (C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 $\Omega$ , input: $t_r$ = $t_f$ = 3 ns)

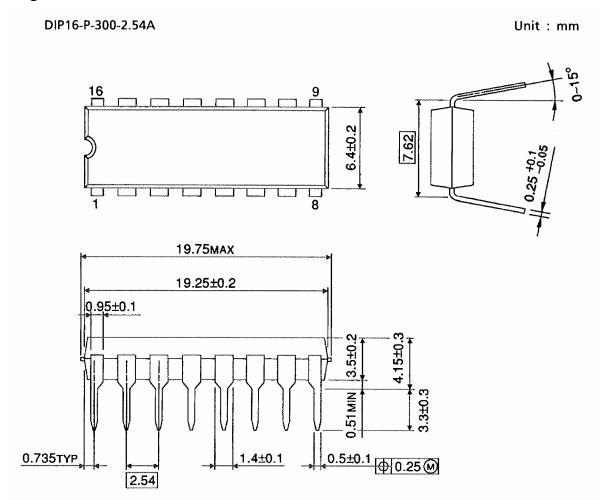
Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
	-,		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay time $(A,B,C\text{-}\overline{Y})$	t <sub>pLH</sub> t <sub>pHL</sub>	_	$3.3 \pm 0.3$ $5.0 \pm 0.5$	_ _	8.5 6.4	14.2 9.2	1.0 1.0	16.3 10.5	ns
Propagation delay time $(G1-\overline{Y}\ )$	t <sub>pLH</sub>	_	$3.3 \pm 0.3$ $5.0 \pm 0.5$	_	7.5 6.1	12.8 8.9	1.0 1.0	14.7 10.2	ns
Propagation delay time	t <sub>pLH</sub>	_	3.3 ± 0.3 5.0 ± 0.5		8.8 7.2	15.0 10.5	1.0 1.0	17.3 12.0	ns
Input capacitance	C <sub>IN</sub>	_		_	5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub>		(Note)	_	143	_	_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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Average operating current can be obtained by the equation:

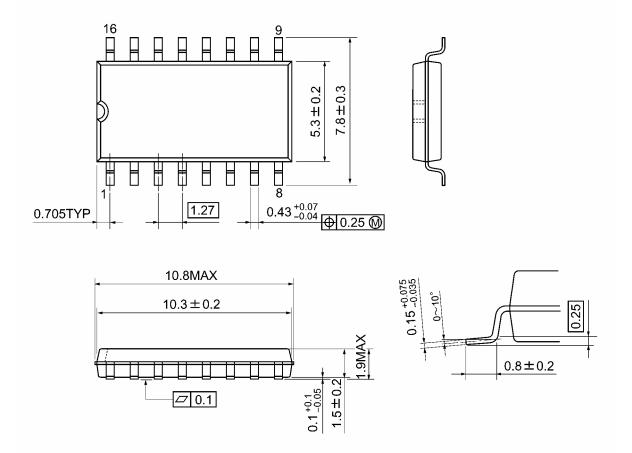
$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$



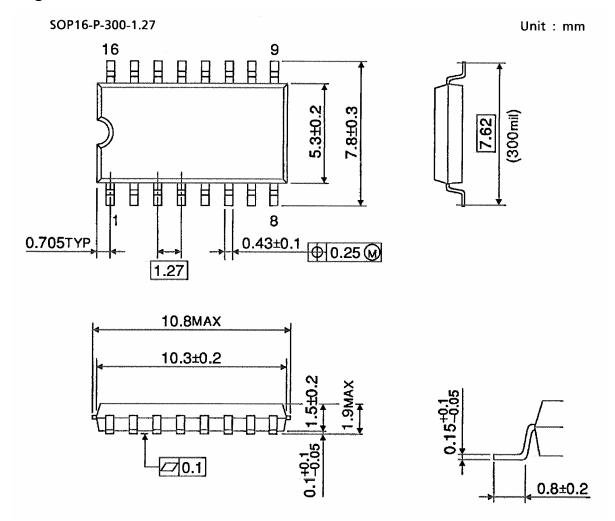
6

Weight: 1.00 g (typ.)

SOP16-P-300-1.27A Unit: mm



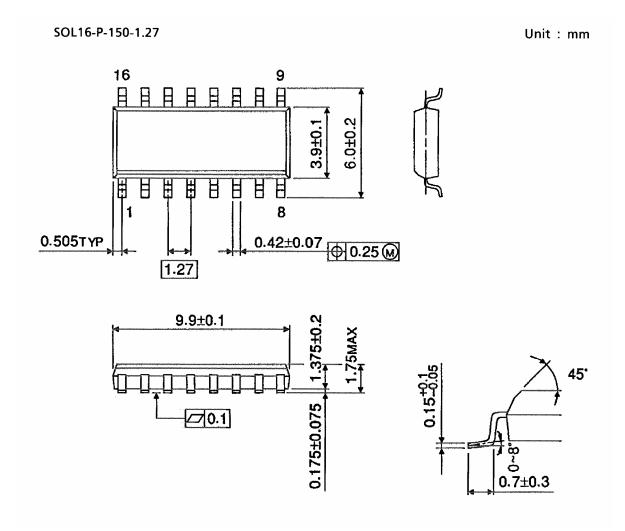
Weight: 0.18 g (typ.)



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Weight: 0.18 g (typ.)

# **Package Dimensions (Note)**

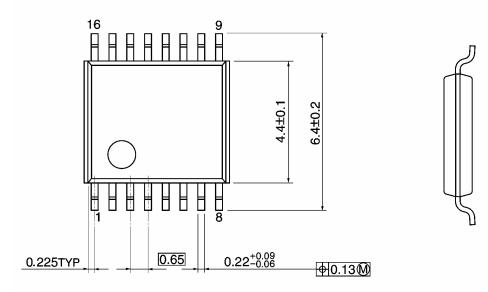


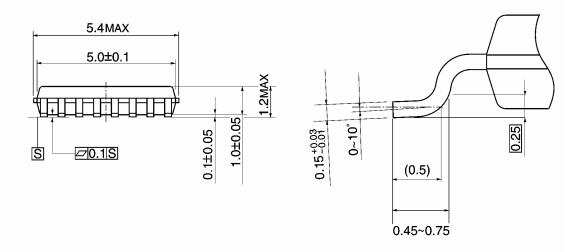
Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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TSSOP16-P-0044-0.65A Unit: mm





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Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages

DIP16-P-300-2.54A SOP16-P-300-1.27A SOL16-P-150-1.27 TSSOP16-P-0044-0.65A

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